FAIRCHILD

SEMICONDUCTOR®

SGL25N120RUF Short Circuit Rated IGBT

General Description

Fairchild's RUF series of Insulated Gate Bipolar Transistors (IGBTs) provides low conduction and switching losses as well as short circuit ruggedness. The RUF series is designed for applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short circuit ruggedness is a required feature.

Features

- Short circuit rated 10 μ s @ T_C = 100°C, V_{GE} = 15V
- High speed switching
- Low saturation voltage : $V_{CE(sat)} = 2.3 \text{ V} @ I_C = 25 \text{ A}$
- High input impedance

Applications

AC & DC motor controls, general purpose inverters, robotics, and servo controls.



Absolute Maximum Ratings $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Description		SGL25N120RUF	Units	
V _{CES}	Collector-Emitter Voltage		1200	V	
V _{GES}	Gate-Emitter Voltage		± 25	V	
I _C	Collector Current	@ $T_{C} = 25^{\circ}C$	40	А	
	Collector Current	@ T _C = 100°C	25	А	
I _{CM (1)}	Pulsed Collector Current		75	Α	
T _{SC} P _D	Short Circuit Withstand Time	@ T _C = 100°C	10	μs	
P _D	Maximum Power Dissipation	@ T _C = 25°C	270	W	
	Maximum Power Dissipation	@ T _C = 100°C	108	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T _J T _{stg}	Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case		0.46	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient		25	°C/W

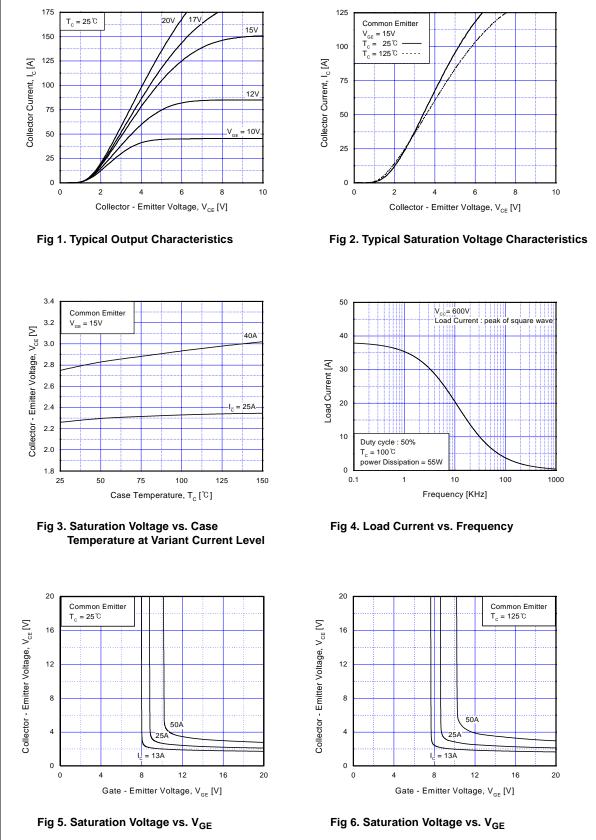
IGBT

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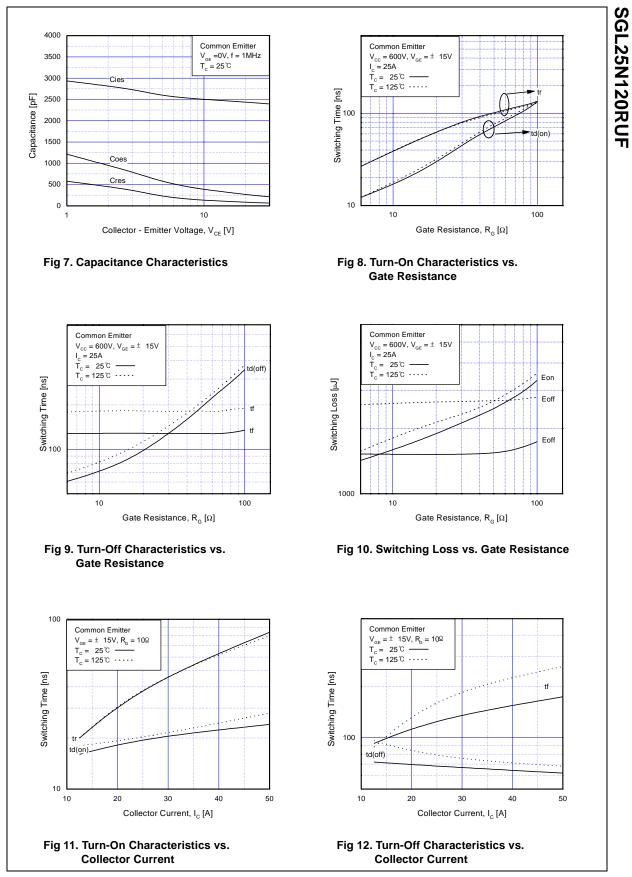
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Cha	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 1mA$	1200			V
$\Delta B_{VCES}/$	Temperature Coefficient of Breakdown			0.0		
ΔT_{J}	Voltage	$V_{GE} = 0V, I_C = 1mA$		0.6		V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			1	mA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$			± 100	nA
On Cha	racteristics					
V _{GE(th)}	G-E Threshold Voltage	I_{C} = 25mA, V_{CE} = V_{GE}	3.5	5.5	7.5	V
	Collector to Emitter	$I_{\rm C} = 25$ A, $V_{\rm GE} = 15$ V		2.3	3.0	V
V _{CE(sat)}	Saturation Voltage	$I_{\rm C} = 40$ A, $V_{\rm GE} = 15$ V		2.8		V
D			1	1	1	
•	c Characteristics			2400		nF
C _{ies}	Output Capacitance	$V_{CE} = 30V, V_{GE} = 0V,$		2400		pF pF
C _{oes} C _{res}	Reverse Transfer Capacitance	f = 1MHz		70		pr pF
Ores				10		рі
Switchi	ng Characteristics	1	1	r.	1	
t _{d(on)}	Turn-On Delay Time	_		30		ns
t _r	Rise Time	_		60		ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 600 \text{ V}, \text{ I}_{C} = 25\text{ A},$		70	130	ns
t _f	Fall Time	$R_{G} = 10\Omega, V_{GE} = 15V,$		150	300	ns
Eon	Turn-On Switching Loss	Inductive Load, $T_C = 25^{\circ}C$		1.60		mJ
E _{off}	Turn-Off Switching Loss	_		1.63		mJ
E _{ts}	Total Switching Loss			3.23	4.55	mJ
t _{d(on)}	Turn-On Delay Time	_		30		ns
t _r	Rise Time	_		70		ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 600 \text{ V}, \text{ I}_{C} = 25\text{A},$		90	165	ns
t _f	Fall Time	$R_{G} = 10\Omega, V_{GE} = 15V,$		200	400	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C		1.88		mJ
E _{off}	Turn-Off Switching Loss	_		2.50		mJ
E _{ts}	Total Switching Loss			4.35	6.31	mJ
T _{sc}	Short Circuit Withstand Time	$V_{CC} = 600 \text{ V}, V_{GE} = 15 \text{ V}$ @ T _C = 100°C	10			μs
Qg	Total Gate Charge			110	165	nC
Q _{ge}	Gate-Emitter Charge	$V_{CE} = 600 \text{ V}, I_C = 25\text{A},$		18	27	nC
Q _{gc}	Gate-Collector Charge	V _{GE} = 15V		55	83	nC
	Internal Emitter Inductance	Measured 5mm from PKG		18		nH

SGL25N120RUF

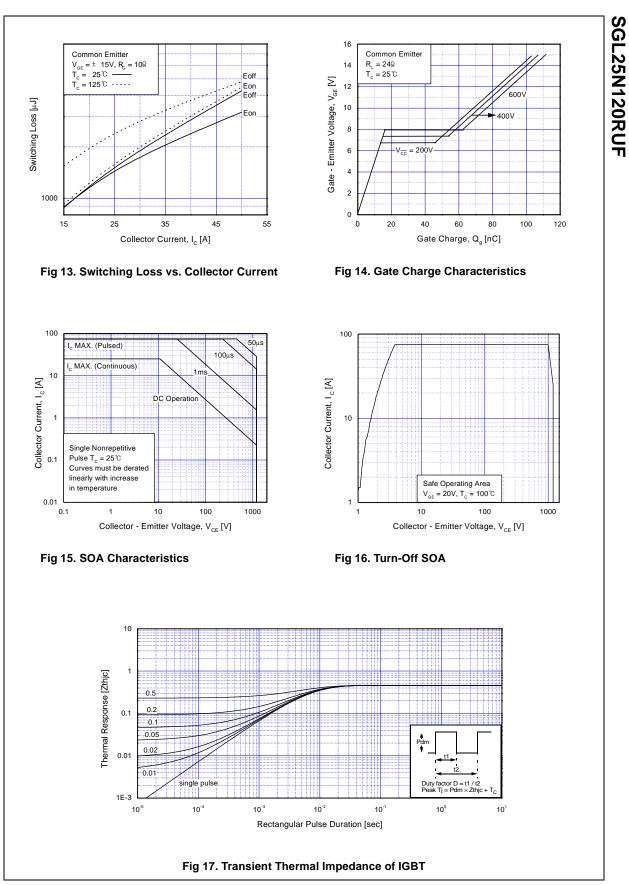




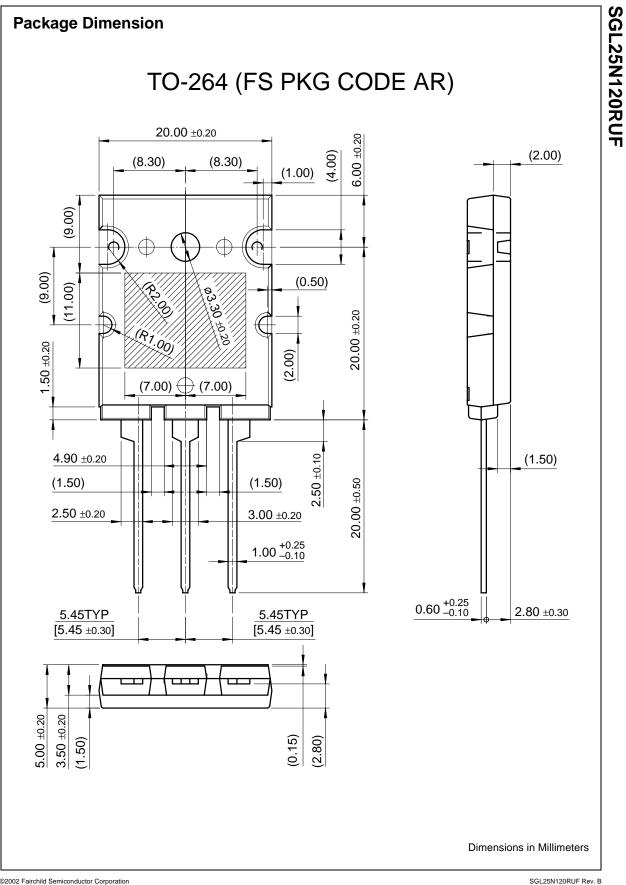
SGL25N120RUF Rev. B



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purpose inverters, robotics, and servo

controls.

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
SGL25N120RUFDTU	Full Production	\$8.73	<u>TO-264</u>	3	RAIL

* 1,000 piece Budgetary Pricing

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Models

Package & leads	Condition	Software version	Revision date
PSPICE			
TO-264-3	Electrical	9.2	Feb 27, 2001

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